1200V 15A Trench and Field Stop IGBT

DESCRIPTION：
- High ruggedness performance
- Low collector to emitter saturation voltage
- Easy parallel switching capability
- Short circuit withstands time 10μs
- RoHS compliant.

TO-247

TYPICAL APPLICATIONS：
- Inverter
- Motor driver

IGBT

MAXIMUM RATINGS (Tvj=25℃ unless otherwise specified)

Characteristic	Condition	Symbol	Value	Unit
Collector-Emitter Voltage		V_{CES}	1200	V
Continuous collector current	Tc=25℃ Tc=100℃	$I_{C\ nom}$	30 15	A
Pulsed collector current	t_P limited by Tvjmax	I_{CM}	60	A
Gate emitter voltage		V_{GE}	±20	V
Short circuit withstand time		t_{SC}	10	us
Power dissipation	Tc=25℃ Tc=100℃	P_{tot}	375 187	W
Temperature under switching conditions		Tvj op	-40~+175	℃
Storage temperature		T_{STG}	-55~+150	℃

THERMAL CHARACTERISTICS

Characteristic	Condition	Symbol	Max.	Unit
IGBT thermal resistance, junction - case		$R_{th(j-C)}$	0.4	K/W
Diode thermal resistance, junction - case		$R_{th(j-C)}$	1.2	K/W
Thermal resistance, junction - ambient		$R_{th(j-A)}$	40	K/W

ELECTRICAL CHARATERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Collector-emitter cut-off current VCE=1200V, VGE=0V Tvj=25℃	I_{CES}			250	uA
Gate-emitter leakage current VCE=0V, VGE=20V Tvj=25℃	I_{GES}			100	nA
Gate-Emitter threshold voltage IC=1.0mA, VGE= VCE Tvj=25℃	$V_{GE(th)}$	5.7	6.2	6.5	V
Collector-Emitter saturation voltage VGE=15V, IC=15A Tvj=25℃ VGE=15V, IC=15A Tvj=175℃	$V_{CE(SAT)}$		1.7 2.2		V
Input capacitance f=1MHz, VCE=30 V, VGE=0 V Tvj=25℃	C_{ies}		1250		pF
Output capacitance f=1MHz, VCE=30 V, VGE=0 V Tvj=25℃	C_{oes}		58		pF
Reverse transfer capacitance f=1MHz, VCE=30 V, VGE=0 V Tvj=25℃	C_{res}		13		pF
Gate charge IC = 15A, VGE = 15 V,VCC =960V Tvj=25℃	Q_G		74		nC
Turn-on delay time IC=15A, VCC=600 V Tvj=25℃ VGE=0/15 V, RG=10Ω Tvj=175℃ (inductive load)	$td_{(ON)}$		22 22		ns
Rise time IC=15A, VCC=600 V Tvj=25℃ VGE=0/15 V, RG=10Ω Tvj=175℃ (inductive load)	tr		34 38		ns
Turn-off delay time IC=15A, VCC=600 V Tvj=25℃ VGE=0/15 V, RG=10Ω Tvj=175℃ (inductive load)	$td_{(OFF)}$		140 166		ns
Fall time IC=15A, VCC=600 V Tvj=25℃ VGE=0/15 V, RG=10Ω Tvj=175℃ (inductive load)	tf		90 146		ns
Turn-on energy IC=15A, VCC=600 V Tvj=25℃ VGE=0/15 V, RG=10Ω Tvj=175℃ (inductive load)	$E_{(ON)}$		0.9 1.1		mJ

Turn-off energy loss per pulse IC=15A, VCC=600 V Tvj=25℃ VGE=0/15 V, RG=10Ω Tvj=175℃ (inductive load)	$E_{(OFF)}$		0.7 1.0		mJ

Diode

MAXIMUM RATINGS (Tvj=25℃ unless otherwise specified)

Characteristic	Condition	Symbol	Value	Unit
Repetitive peak reverse voltage	Tvj=25℃	V_{RRM}	1200	V
Continuous forward current	Tc=100℃	I_F	15	A
Diode maximum current	t_P limited by Tvj max	I_{FM}	60	A

ELECTRICAL CHARATERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Forward voltage IF=15A, VGE=0 V Tvj=25℃ IF=15A, VGE=0 V Tvj=175℃	V_F		2.3 1.9		V
Reverse Recovered Time IF=15 A, Tvj=25℃ -diF/dt =250A/μs Tvj=175℃ VR=600 V	T_{rr}		233 396		ns
Peak reverse recovery current IF=15 A, Tvj=25℃ -diF/dt =250A/μs Tvj=175℃ VR=600 V	I_{RRM}		8 11		A
Reverse Recovered charge IF=15 A, Tvj=25℃ -diF/dt =250A/μs Tvj=175℃ VR=600 V	Q_{rr}		718 1700		nC

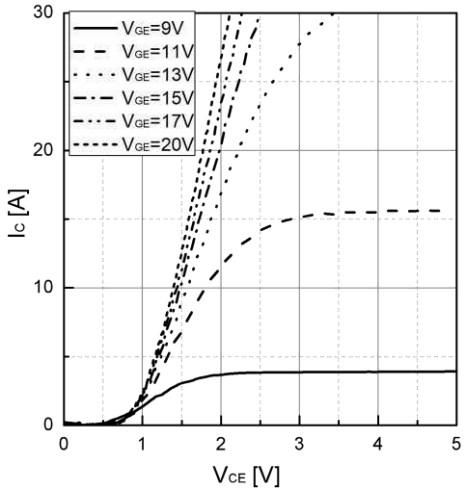


Figure 1. Typical output characteristics (Tvj=25℃)

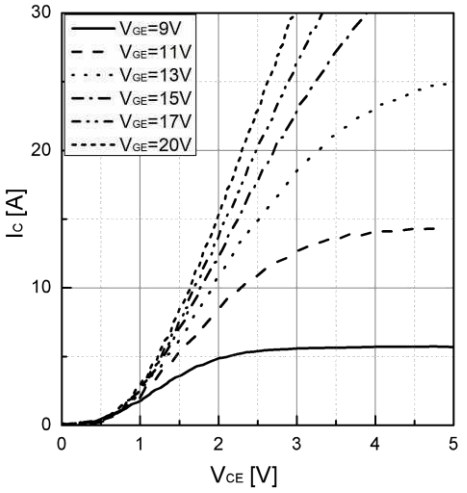


Figure 2. Typical output characteristics (Tvj=175℃)

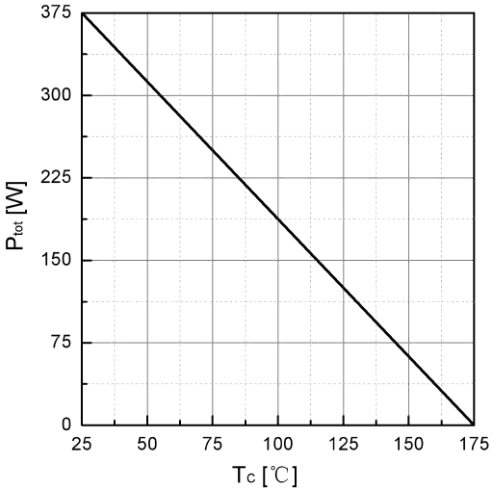


Figure 3. Power dissipation as a function of TC

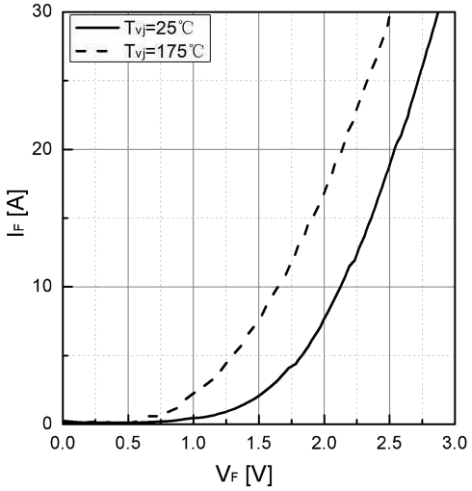


Figure 4. Typical IF as a function of VF

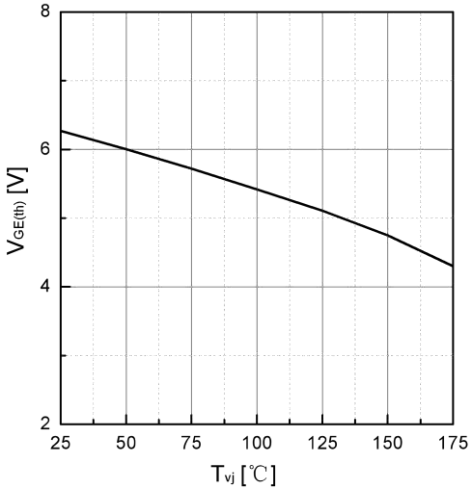


Figure 5. Typical VGE(th) as a function of Tvj (I_C=1mA)

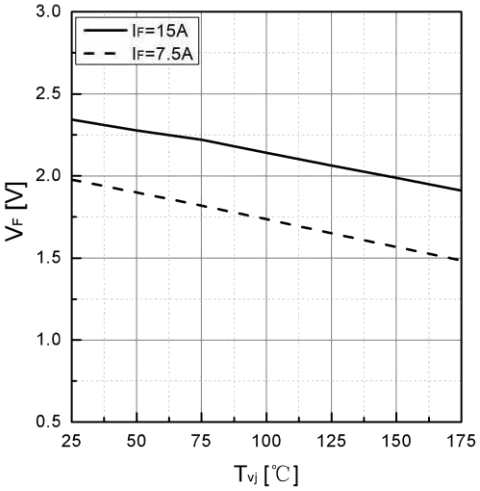


Figure 6. Typical VF as a function of Tvj

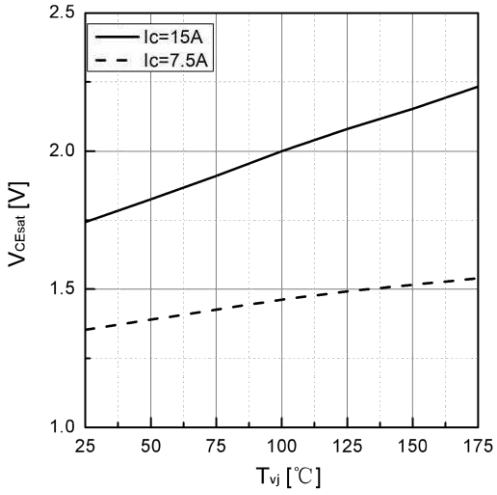


Figure 7. Typical VCEsat as a function of Tvj

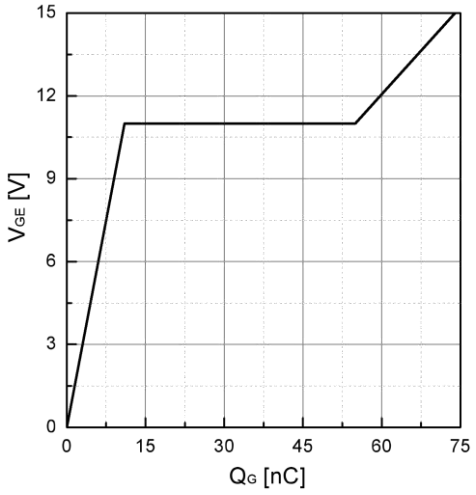


Figure 8. Typical Gate charge

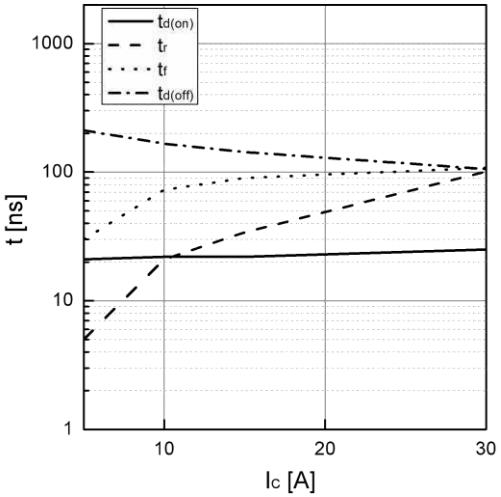


Figure 9. Typical switching times as a function of IC

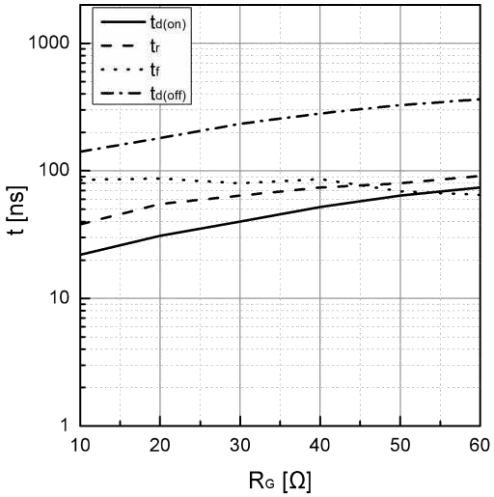


Figure 10. Typical switching times as a function of RG

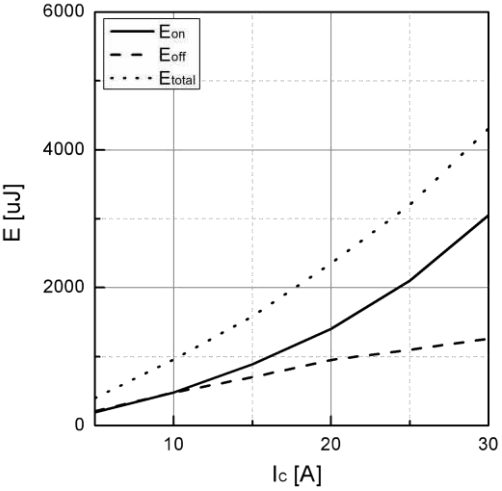


Figure 11. Typical switching energy losses as a function of IC

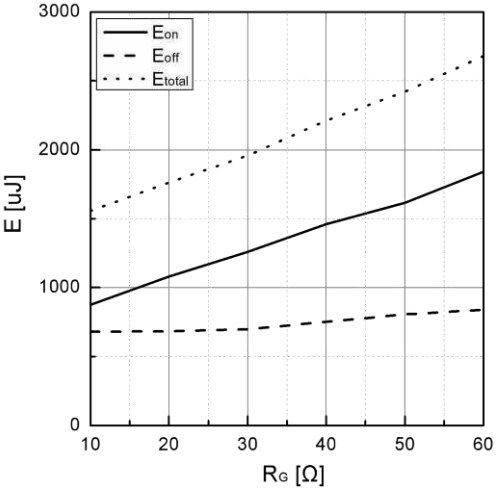


Figure 12. Typical switching energy losses as a function of RG

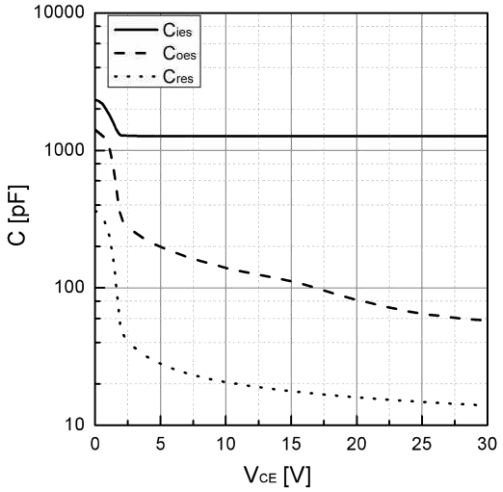


Figure 13. Typical capacitance as a function of VCE
(f=1Mhz, VGE=0V)

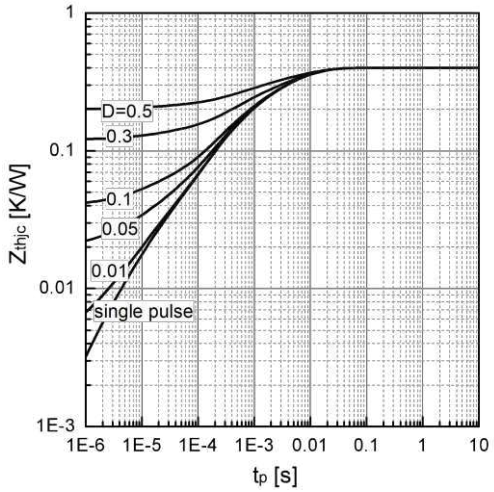
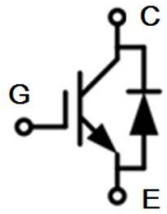
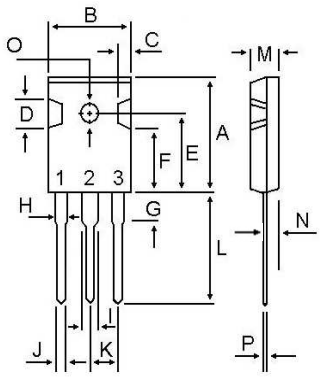


Figure 14. Transient thermal impedance, IGBT

• Circuit diagram



• Package outlines : Dimensions in (mm)



DIM	MILLIMETERS	
	MIN	MAX
A	20.80	21.80
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.50	15.50
F	11.20	13.20
G	3.75	4.35
H	1.90	2.30
I	2.90	3.30
J	1.00	1.40
K	5.26	5.66
L	19.50	20.50
M	4.68	5.36
N	2.30	2.60
O	3.45	3.85
P	0.48	0.72

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